

GaAs pHEMT MMIC 1 WATT POWER AMPLIFIER, DC - 22 GHz



Typical Applications

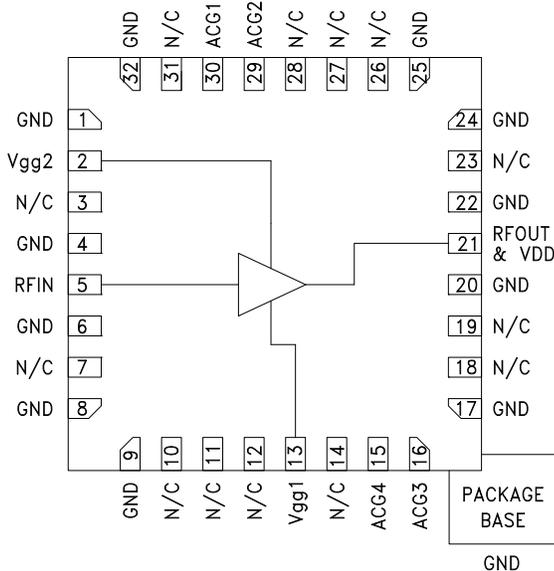
The HMC797LP5E is ideal for:

- Test Instrumentation
- Microwave Radio & VSAT
- Military & Space
- Telecom Infrastructure
- Fiber Optics

Features

- High P1dB Output Power: 28 dBm
- High Psat Output Power: 29.5 dBm
- High Gain: 13.5 dB
- High Output IP3: 39 dBm
- Supply Voltage: +10 V @ 400 mA
- 50 Ohm Matched Input/Output
- 32 Lead 5x5 mm SMT Package: 25 mm²

Functional Diagram



General Description

The HMC797LP5E is a GaAs MMIC pHEMT Distributed Power Amplifier which operates between DC and 22 GHz. The amplifier provides 13.5 dB of gain, 39 dBm output IP3 and +28 dBm of output power at 1 dB gain compression while requiring 400 mA from a +10 V supply. This versatile PA exhibits a positive gain slope from 4 to 20 GHz making it ideal for EW, ECM, Radar and test equipment applications. The HMC797LP5E amplifier I/Os are internally matched to 50 Ohms facilitating integration into multi-chip-modules (MCMs), is packaged in a leadless QFN 5x5 mm surface mount package, and requires no external matching components.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{dd} = +10\text{V}$, $V_{gg2} = +3.5\text{V}$, $I_{dd} = 400\text{mA}^*$

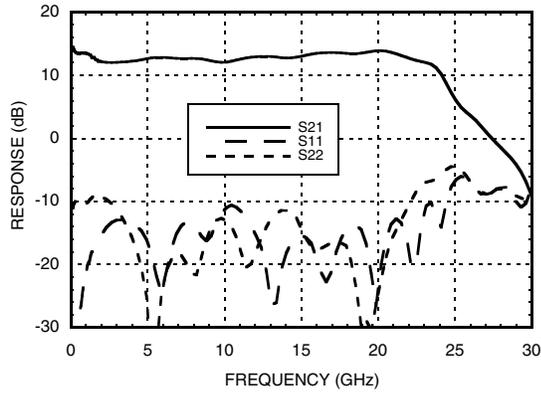
| Parameter | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. | Units |
|---|---------|-------|------|---------|-------|------|---------|-------|------|-------|
| Frequency Range | DC - 12 | | | 12 - 18 | | | 18 - 22 | | | GHz |
| Gain | 11 | 12.5 | | 11 | 13.5 | | 11 | 13.5 | | dB |
| Gain Flatness | | ±0.7 | | | ±0.5 | | | ±0.5 | | dB |
| Gain Variation Over Temperature | | 0.012 | | | 0.008 | | | 0.008 | | dB/°C |
| Input Return Loss | | 13 | | | 15 | | | 15 | | dB |
| Output Return Loss | | 12 | | | 16 | | | 13 | | dB |
| Output Power for 1 dB Compression (P1dB) | 26 | 28 | | 25 | 27 | | 23.5 | 25.5 | | dBm |
| Saturated Output Power (Psat) | | 29.5 | | | 29 | | | 27 | | dBm |
| Output Third Order Intercept (IP3) | | 39 | | | 37 | | | 35 | | dBm |
| Noise Figure | | 3.5 | | | 4 | | | 6 | | dB |
| Supply Current (Idd) (Vdd= 10V, Vgg1= -0.8V Typ.) | | 400 | 440 | | 400 | 440 | | 400 | 440 | mA |

* Adjust Vgg1 between -2 to 0 V to achieve Idd = 400 mA typical.

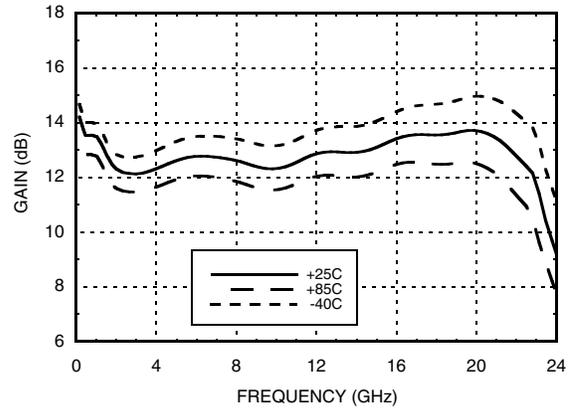


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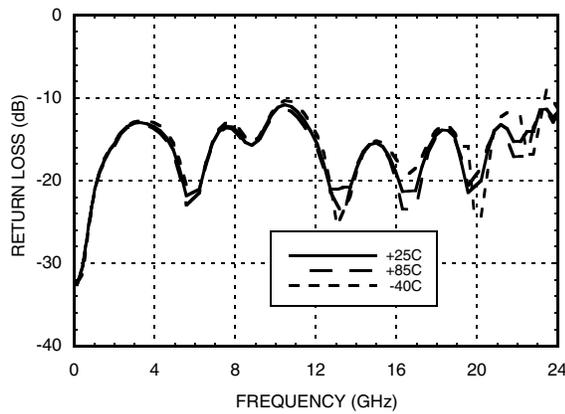
Gain & Return Loss



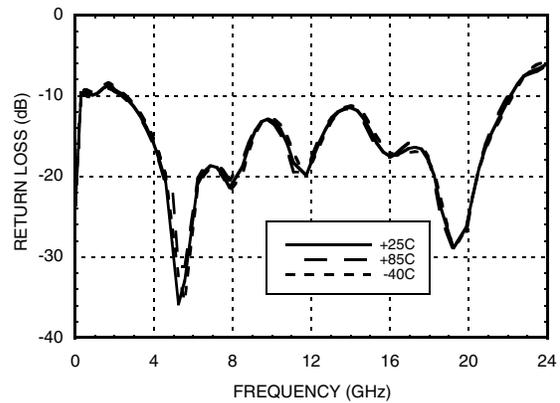
Gain vs. Temperature



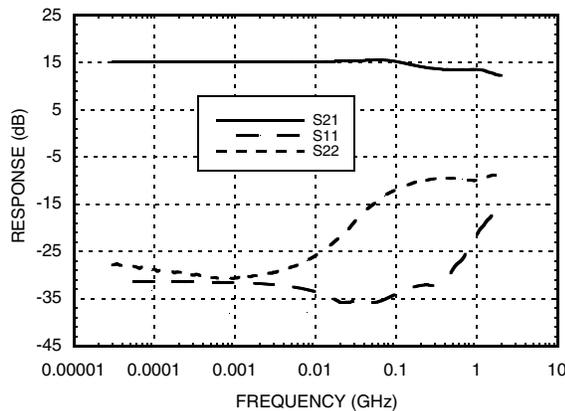
Input Return Loss vs. Temperature



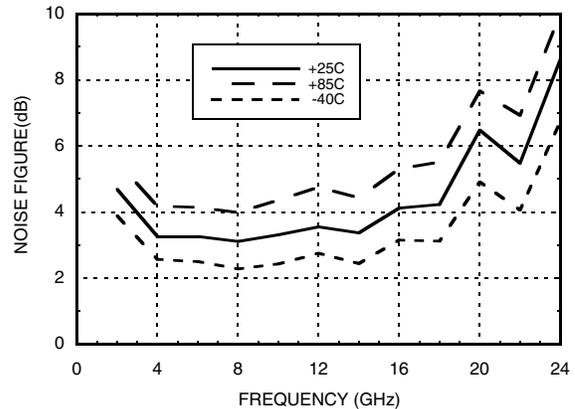
Output Return Loss vs. Temperature



Low Frequency Gain & Return Loss



Noise Figure vs. Temperature



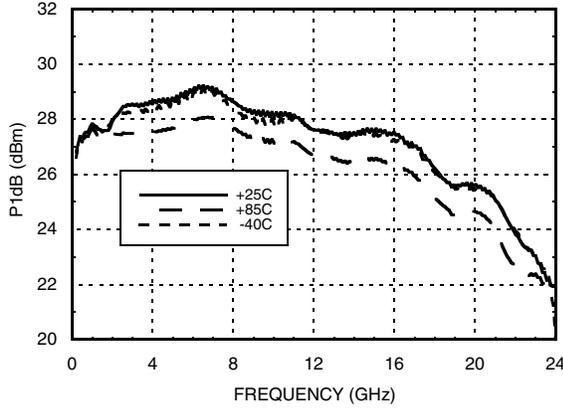
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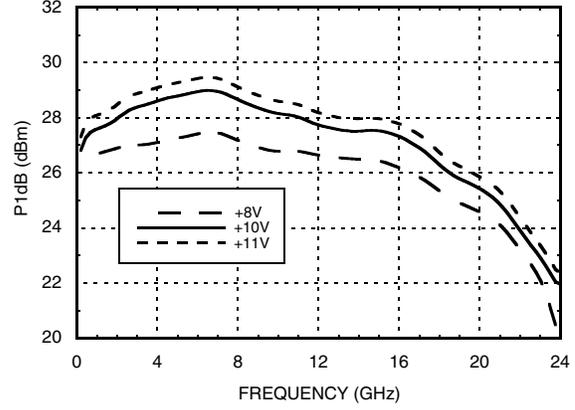


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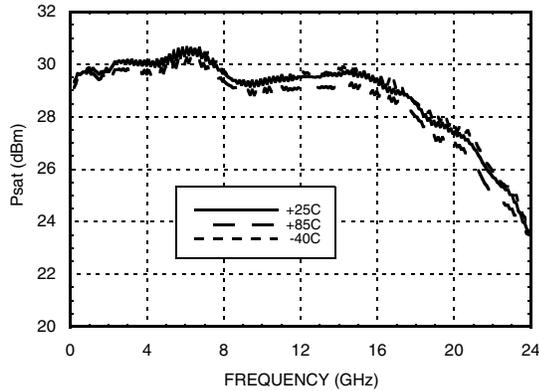
P1dB vs. Temperature



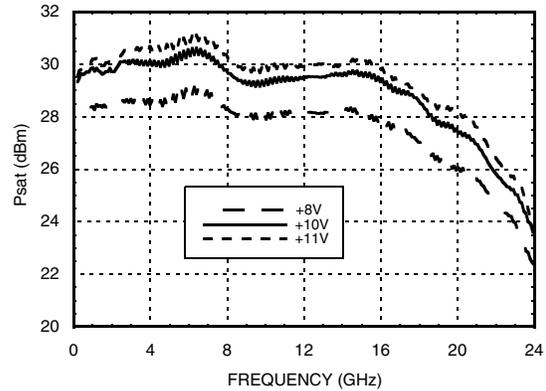
P1dB vs. Supply Voltage



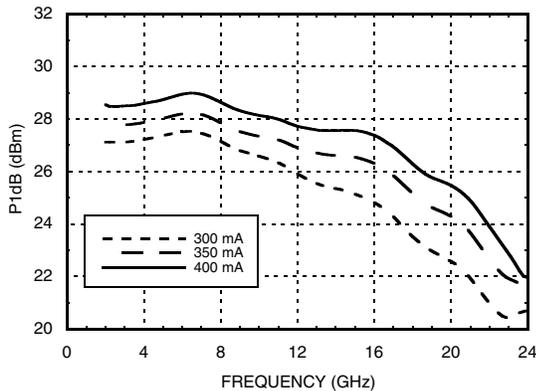
Psat vs. Temperature



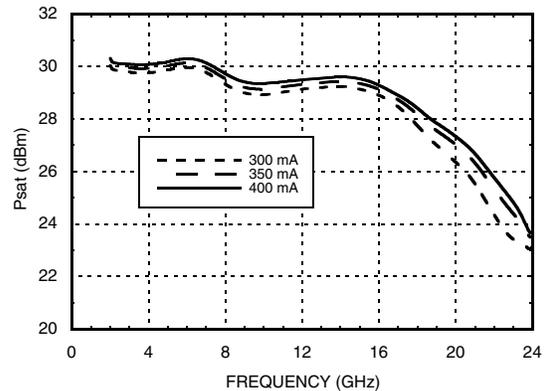
Psat vs. Supply Voltage



P1dB vs. Supply Current



Psat vs. Supply Current



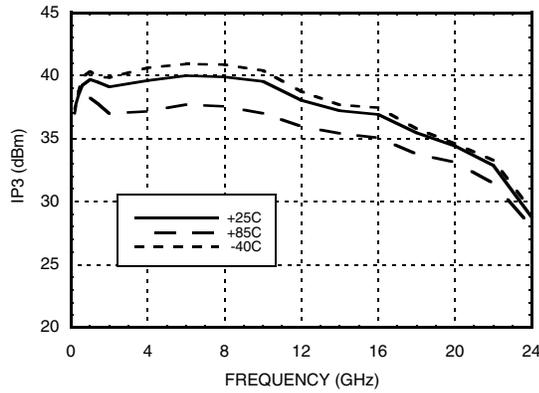
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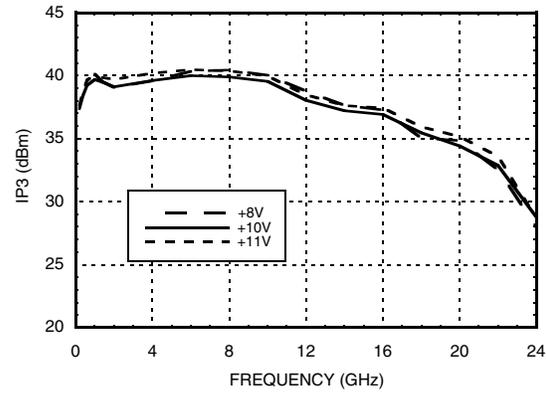
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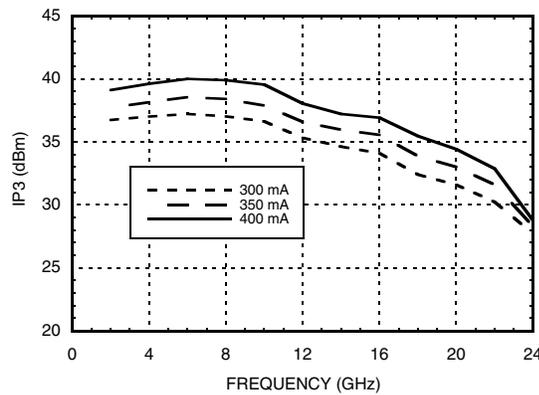
**Output IP3 vs.
Temperature @ Pout = 18 dBm / Tone**



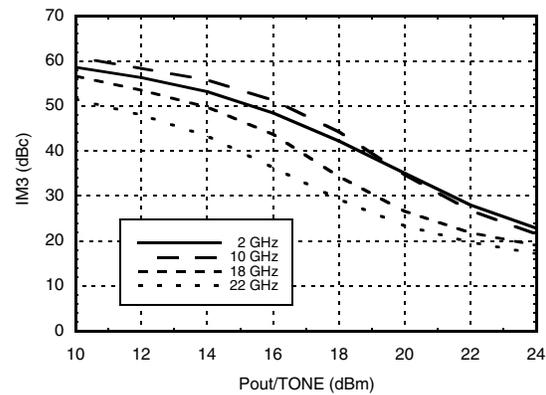
**Output IP3 vs.
Supply Voltage @ Pout = 18 dBm / Tone**



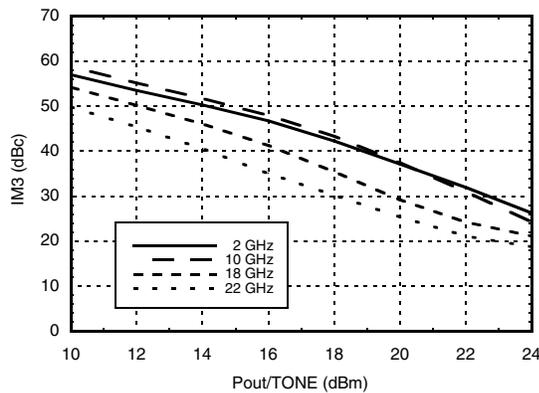
**Output IP3 vs.
Supply Currents @ Pout = 18 dBm / Tone**



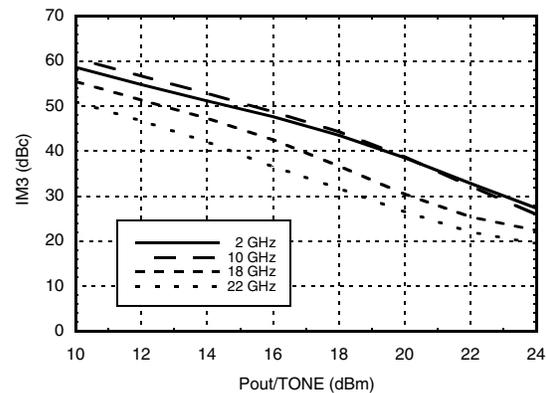
Output IM3 @ Vdd = +8V



Output IM3 @ Vdd = +10V



Output IM3 @ Vdd = +11V



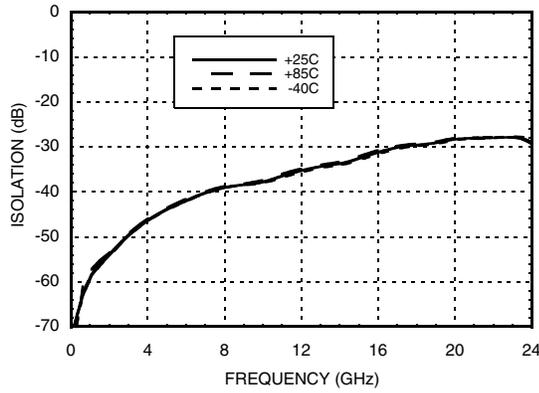
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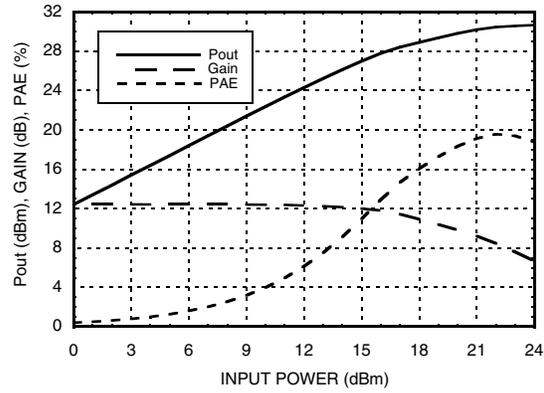


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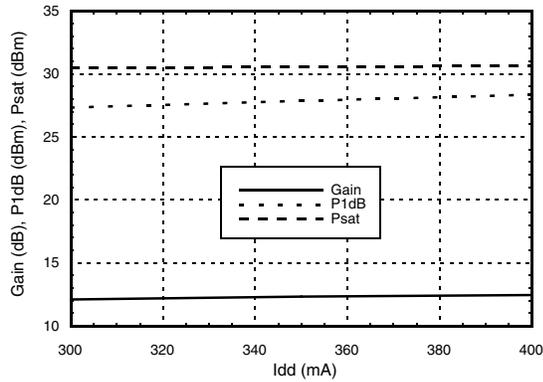
Reverse Isolation vs. Temperature



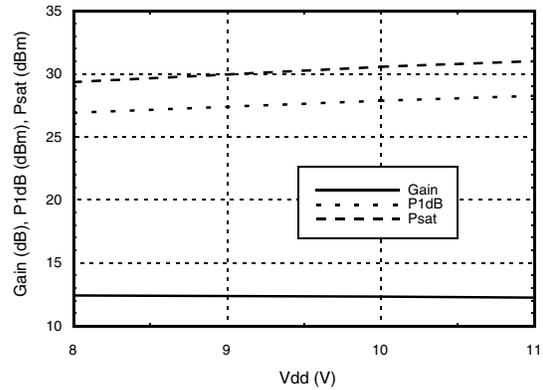
Power Compression @ 10 GHz



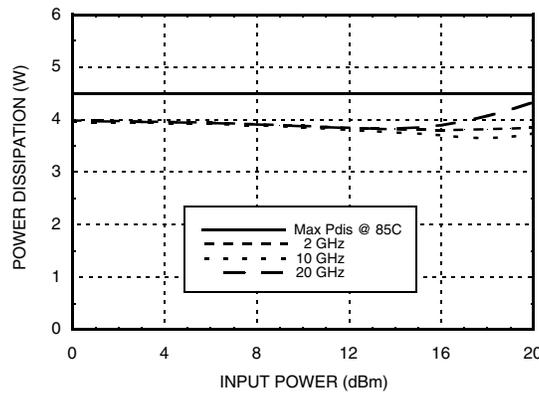
Gain & Power vs. Supply Current @ 10 GHz



Gain & Power vs. Supply Voltage @ 10 GHz



Power Dissipation



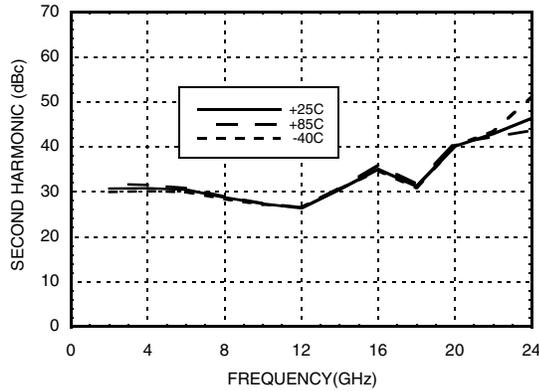
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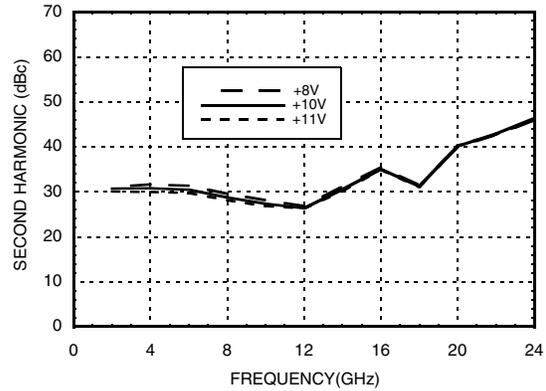


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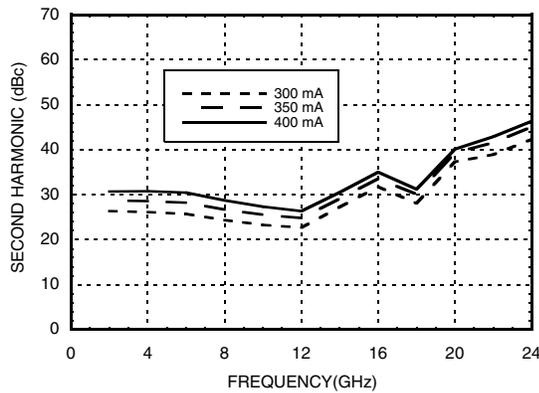
Second Harmonics vs. Temperature
@ $P_{out} = 18 \text{ dBm}$, $V_{dd} = 10\text{V}$ & $V_{gg} = 3.5\text{V}$



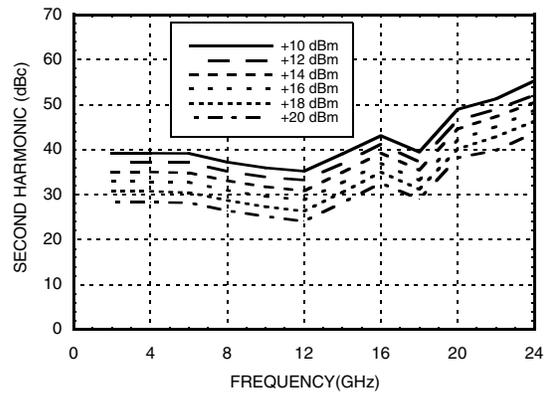
Second Harmonics vs. V_{dd}
@ $P_{out} = 18 \text{ dBm}$, $I_{dd} = 400 \text{ mA}$ [1]



Second Harmonics vs. I_{dd}
@ $P_{out} = 18 \text{ dBm}$, $V_{gg2} = 3.5\text{V}$



Second Harmonics vs. P_{out}
 $V_{dd} = 10\text{V}$ & $V_{gg} = 3.5\text{V}$ & $I_{dd} = 400 \text{ mA}$



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Absolute Maximum Ratings

| | |
|---|-------------------------------------|
| Nominal Drain Supply to GND | +12.0 V |
| Gate Bias Voltage (V _{gg1}) | -3.0 to 0 Vdc |
| Gate Bias Current (I _{gg1}) | < +10 mA |
| Gate Bias Voltage (V _{gg2}) | +2.0 V to (V _{dd} - 6.5 V) |
| Gate Bias Current (I _{gg2}) | < +10 mA |
| Continuous P _{diss} (T = 85 °C) (derate 69 mW/°C above 85 °C) | 4.5 W |
| RF Input Power | +27 dBm |
| Output Power into VSWR >7:1 | +29 dBm |
| Storage Temperature | -65 to 150 °C |
| Max Peak Reflow Temperature | 260 °C |
| ESD Sensitivity (HBM) | Class 1A |

Reliability Information

| | |
|--|---------------|
| Junction Temperature to Maintain 1 Million Hour MTTF | 150 °C |
| Nominal Junction Temperature (T=85 °C, V _{dd} = 10 V) | 144 °C |
| Thermal Resistance (channel to ground paddle) | 14.6 °C/W |
| Operating Temperature | -40 to +85 °C |

9

AMPLIFIERS - LINEAR & POWER - SMT

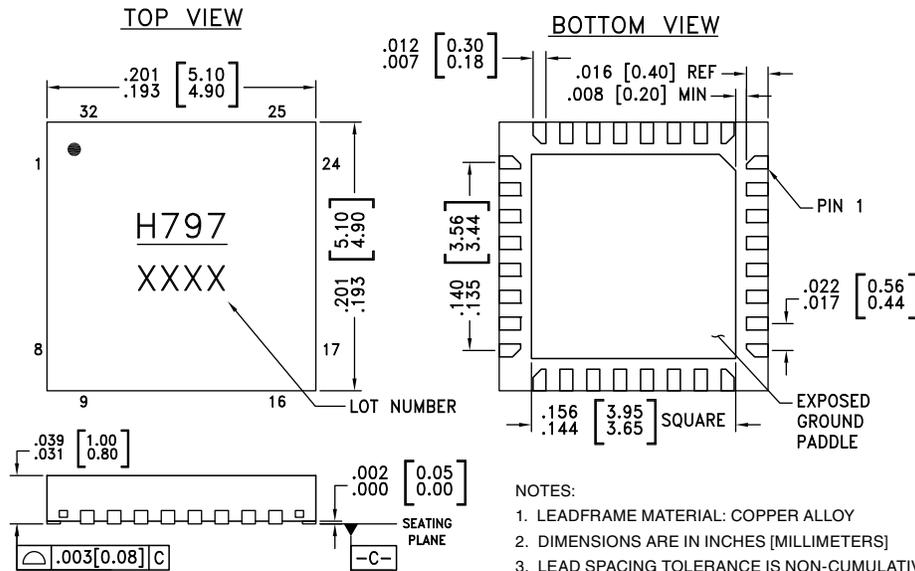


ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Typical Supply Current vs. V_{dd}

| V _{dd} (V) | I _{dd} (mA) |
|---------------------|----------------------|
| +9 | 400 |
| +10 | 400 |
| +11 | 400 |

Outline Drawing



Package Information

| Part Number | Package Body Material | Lead Finish | MSL Rating | Package Marking ^[1] |
|-------------|--|---------------|---------------------|--------------------------------|
| HMC797LP5E | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL1 ^[2] | H797 XXXX |

[1] 4-Digit lot number XXXX

[2] Max peak reflow temperature of 260 °C

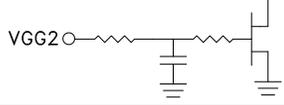
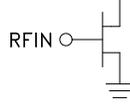
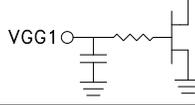
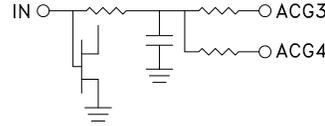
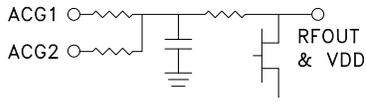
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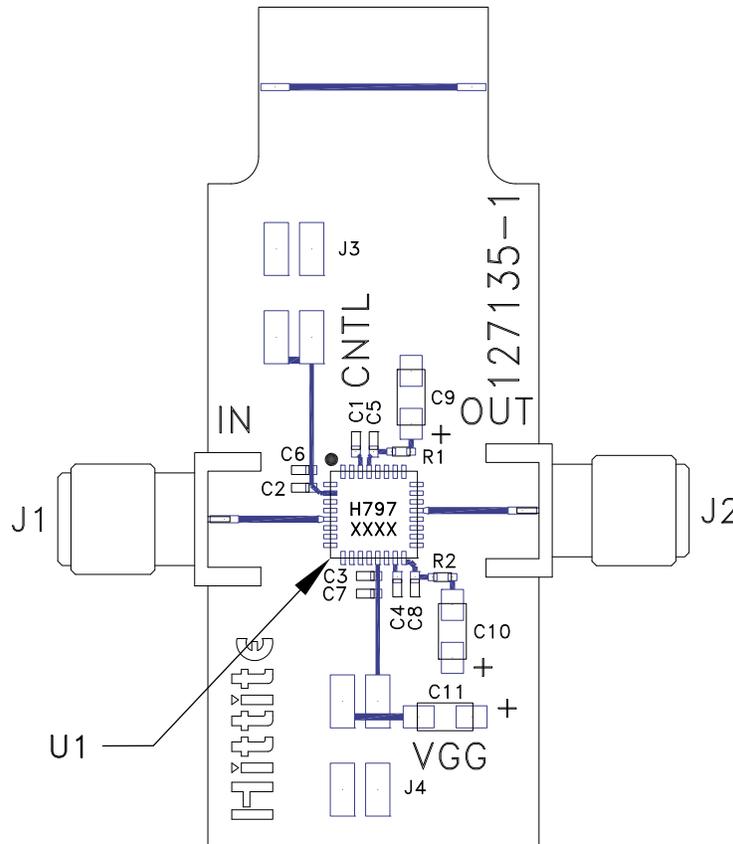
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Pin Descriptions

| Pin Number | Function | Description | Interface Schematic |
|---|-------------|--|---|
| 1, 4, 6, 8, 9, 17, 20, 22, 24, 25, 32 Package Bottom | GND | These pins & exposed ground paddle must be connected to RF/DC ground. |  |
| 2 | VGG2 | Gate control 2 for amplifier. Attach bypass capacitor per application circuit herein. For nominal operation +3.5V should be applied to Vgg2. |  |
| 3, 7, 10 - 12, 14, 18, 19, 23, 26 - 28, 31 | N/C | No connection required. These pins may be connected to RF/DC ground without affecting performance. | |
| 5 | RFIN | This pad is DC coupled and matched to 50 Ohms. Blocking capacitor is required. |  |
| 13 | VGG1 | Gate control 1 for amplifier. Attach bypass capacitor per application circuit herein. Please follow "MMIC Amplifier Biasing Procedure" application note. |  |
| 15 | ACG4 | Low frequency termination. Attach bypass capacitor per application circuit herein. |  |
| 16 | ACG3 | | |
| 21 | RFOUT & VDD | RF output for amplifier. Connect DC bias (Vdd) network to provide drain current (Idd). See application circuit herein. |  |
| 29 | ACG2 | Low frequency termination. Attach bypass capacitor per application circuit herein. | |
| 30 | ACG1 | | |


**GaAs pHEMT MMIC
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Evaluation PCB

List of Materials for Evaluation PCB 130784 [1]

| Item | Description |
|----------|-----------------------------|
| J1, J2 | SMA Connectors |
| J3, J4 | DC Pins |
| C1 - C4 | 100 pF Capacitor, 0402 Pkg. |
| C5, C8 | 10 kpF Capacitor, 0402 Pkg. |
| C9 - C11 | 4.7 µF Capacitor, Tantalum |
| R1, R2 | 0 OHM Resistor, 0402 Pkg |
| U1 | HMC797LP5E Power Amplifier |
| PCB [2] | 127135 Evaluation PCB |

[1] Reference this number when ordering complete evaluation PCB

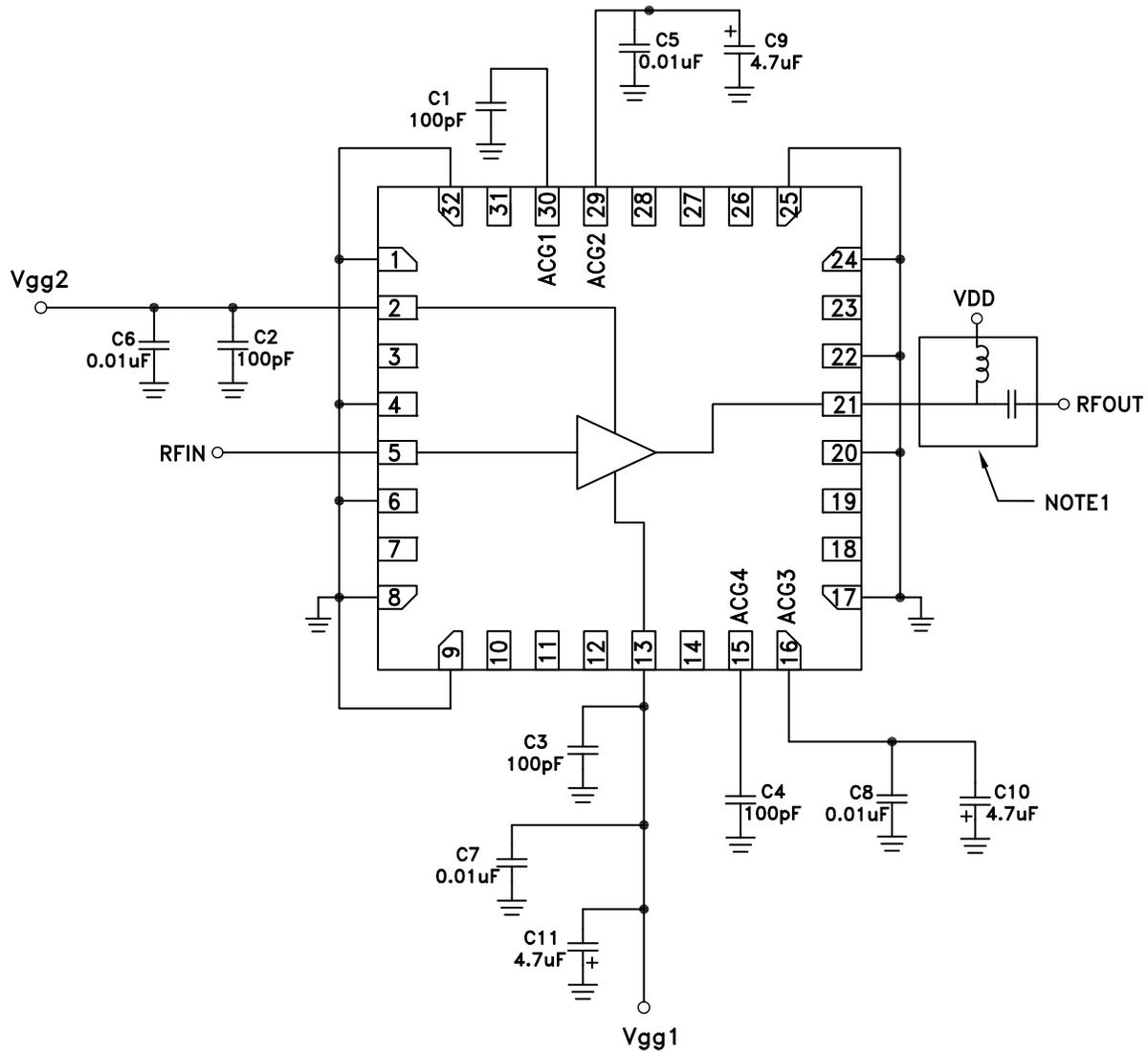
[2] Circuit Board Material: Rogers 4350 or Arlon FR4

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

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Application Circuit



NOTE 1: Drain Bias (Vdd) must be applied through a broadband bias tee or external bias network.

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